An enhanced switching policy for buck-derived multi-level switching power amplifiers
Garcia i Tormo, A.; Poveda, A.; Alarcon, E.; Bergveld, H.J.; Buter, B.; Karadi, R.

Published in:

DOI:
10.1109/ISCAS.2010.5537945

Published: 01/01/2010

Document Version
Publisher’s PDF, also known as Version of Record (includes final page, issue and volume numbers)

Please check the document version of this publication:
- A submitted manuscript is the author's version of the article upon submission and before peer-review. There can be important differences between the submitted version and the official published version of record. People interested in the research are advised to contact the author for the final version of the publication, or visit the DOI to the publisher's website.
- The final author version and the galley proof are versions of the publication after peer review.
- The final published version features the final layout of the paper including the volume, issue and page numbers.

Link to publication

Citation for published version (APA):

General rights
Copyright and moral rights for the publications made accessible in the public portal are retained by the authors and/or other copyright owners and it is a condition of accessing publications that users recognise and abide by the legal requirements associated with these rights.

- Users may download and print one copy of any publication from the public portal for the purpose of private study or research.
- You may not further distribute the material or use it for any profit-making activity or commercial gain
- You may freely distribute the URL identifying the publication in the public portal?

Take down policy
If you believe that this document breaches copyright please contact us providing details, and we will remove access to the work immediately and investigate your claim.
An Enhanced Switching Policy for Buck-Derived Multi-Level Switching Power Amplifiers

Albert Garcia i Tormo, Alberto Poveda, Eduard Alarcón
Department of Electronic Engineering
Technical University of Catalonia
08034 Barcelona, Spain
E-mail: agarcia@eel.upc.edu

Henk Jan Bergveld, Berry Buter, Ravi Karadi
NXP Semiconductors, Corporate I&T, Research
High Tech Campus 32
5656AE Eindhoven, The Netherlands

Abstract—This work proposes a switching policy for multi-level full-bridge switching power converters and analyses their performance by driving them with a multi-level PWM modulation, targeting high-efficiency power amplifiers. Unlike conventional policies, which generate the output voltage levels only from the values of the supply voltages, this enhanced policy also uses the values of the voltage difference between supply voltages to generate additional output voltage levels, therefore maximising the number of output voltage levels for a given set of supply voltages and connection switches. Simulation results show that, when tracking a band-limited signal, the proposed switching policy can reduce the power of the high-frequency spectral content from 21% to 11% by upgrading a 5-level amplifier to a 7-level amplifier without adding supply voltages or connection switches.

I. INTRODUCTION AND MOTIVATION

Switching amplifiers are becoming the most popular power amplifiers in almost all applications [1], [2]. Their high efficiency and reduced size make them very suitable not only for mobile applications, wherein size and power consumption are key features, but also for high-power applications, because of reliability and the size and weight (i.e. cost) of the heat sink.

In both high and low-power applications, the external LC filter has a significant impact upon the amplifier size, cost and efficiency, since the inductors are in the power path. In pursuit of simplifying the filtering process, and thereby improve these features, this work explores multi-level amplification.

By using a multi-level output stage, the power of the high-frequency components, i.e. the spectral content at frequencies beyond the reference signal bandwidth, is reduced. Therefore less filtering effort is required to achieve the desired performance. If enough levels are used, even filter-less amplification becomes feasible.

The performance of multi-level amplification improves as the number of levels increase [1], although this increase generally involves adding supply voltages and connection switches. The proposed switching policy allows maximising the number of output voltage levels without adding connection switches, for a given set of supply voltages.

Most devices include a power-management unit which provides several supply voltages (Figure 1). A multi-level amplifier can take advantage of any available supply voltage present in a certain system, yet by employing the proposed switching policy it is possible to take further advantage of all the available power resources.

In section II, two multi-level converter topologies for switching amplifiers are presented and analysed, as well as the proposed switching policy. In order to take advantage of this policy and drive the multi-level converters as amplifiers, a native multi-level modulation must be used (section III). The performance achieved by the multi-level amplifiers employing the proposed switching policy is characterised and compared with state-of-the-art multi-level amplifiers (section IV). Finally conclusions are drawn (section V).

In what follows, the signal to track and power-amplify (amplifier input) is denoted reference signal or $x(t)$, the discrete-amplitude signal (the signal supplied by the switches at the input of the power filter) is denoted encoded signal or $z(t)$ and the output signal (amplifier output) is denoted recovered signal or $\tilde{x}(t)$, see Figure 1.

II. MULTI-LEVEL CONVERTER TOPOLOGIES FOR SWITCHING AMPLIFIERS AND PROPOSED SWITCHING POLICY

Conventional switching amplifiers are based on a buck or a full-bridge converter, because they are linear. Similarly, the multi-level amplifiers are based on the multi-level version of a buck or a full-bridge converter.

Both the buck and the full-bridge converters use both the ground voltage and the supply voltage (namely $GND$ and $V_{DD}$) provided by the power supply to generate, through connection switches, a 2-level discrete-amplitude signal which is subsequently filtered out by a low-pass LC filter. The output of this filter is connected to the load. The multi-level versions of these converters add connection switches between the input of the filter and each additional supply voltage, so that the discrete-amplitude signal may comprise more levels.

In what follows, for the sake of notation simplicity, both the reactive filter and the load have been merged into a complex load.
Z_{CL} with two ends (Figure 2). This complex load may comprise a differential-mode filter, a common-mode filter (as in Figure 2), both of them or none (filter-less).

A. Multi-Level Back Converter

In a multi-level buck converter, the complex load positive end is connected to all supply voltages through connection switches and the \( R_L \) negative end is grounded (as in Figure 2 but grounding the \( R_L \) negative end). In this way, the discrete amplitude signal can comprise up to as many distinct levels as distinct supply voltages.

When using \( n \) \((\geq 0, n \in \mathbb{N})\) additional supply voltages besides \( \text{GND} \) and \( V^+_0 \) \((n + 2)\) supply voltages), the number of required connection switches and the maximum number of distinct output voltage levels is \( n + 2 \), given that each supply voltage of value \( V^+_0 \) provides an output voltage level of value \( V^+_0 \). The output voltage is always positive if all the supply voltages are positive.

B. Multi-Level Full-Bridge Converter

In a full-bridge converter the \( R_L \) negative end is not grounded; instead it is symmetrically supplied with another buck converter (see Figure 2). The output voltage \( V_{\text{CL}} \) is therefore floating (differential-mode output) and thus a dedicated common-mode filter may be required in some applications. Yet, given a set of supply voltages and compared to the multi-level buck topology, this topology doubles the output voltage dynamic range.

The multi-level full-bridge converter uses one connection switch between each end of the complex load and each supply voltage\(^1\). Therefore, a converter using \( n + 2 \) supply voltages requires \( 2 \cdot n + 4 \) connection switches, see Figure 2.

Even if all supply voltages are positive\(^2\), the complex load is supplied with a bipolar discrete-amplitude signal. The complex load ends are driven by a bipolar differential-mode voltage and by an unipolar common-mode voltage (positive if so are all supply voltages). Moreover, because of the differential output, the number of distinct output voltage levels not only depends upon the number and the value of the supply voltages, but also upon the switching policy, as described in the next section.

\(^1\)With only one power supply (i.e. two supply voltages, \( \text{GND} \) and \( V^+_0 \)) the full-bridge converter is already multi-level capable, since three distinct output voltage levels are possible (of \( \pm V^+_0 \) and \( \text{GND} \) values).

\(^2\)In a full-bridge converter, the polarity of the output voltage is continuously reversed, hence negative supply voltages yield the same output voltage levels as positive ones. In order to get distinct output voltage levels, their absolute value must be different \( |V^+_0| \neq |V^-_0| \) if \( i \neq j \). Still, negative supply voltages do modify the common-mode voltage at the complex load ends.

Figure 2. Multi-level full-bridge converter \((n + 2)\) supply voltages. The complex load comprises a common-mode filter and the switches \((S_i, S'_i)\) have been synthesised with power MOSFETs. If the \( R_L \) negative end is grounded, this converter simplifies to the multi-level buck topology.

Figure 3. Significant time waveforms of multi-level PWM. Example with two power supplies employing a conventional policy (five levels, upper graph) and employing the proposed policy (seven levels, lower graph), conveniently selecting \( V^+_0 \) for equally distributed output voltage levels in each case.

C. Output Voltage Levels and Switching Policy

Let us consider a system with a main power supply (which provides \( \text{GND} \) and \( V^+_0 \)) and a power-management unit, which provides \( n \) additional different supply voltages \((n \geq 0, n \in \mathbb{N})\). There are \( n + 2 \) different available supply voltages in this system (Figure 2). In the multi-level full-bridge topology, because of the two subsets of switches, it is possible to apply any available supply voltage \((\text{GND}, V^-_0, \ldots, V^-_0)\) at each end of the complex load.

The conventional switching policies always set one end of \( Z_{CL} \) to \( \text{GND} \) (either the positive or the negative), so that the output voltage levels only comprise the values of the supply voltages (and the symmetrical negative values). The proposed policy sets both ends to any voltage, so that the output voltage levels also comprise the values of the voltage difference between supply voltages.

Let us consider a simple example, a system with three different supply voltages: \( V^-_1, V^-_1 \) and \( \text{GND} \). By setting the negative end of \( Z_{CL} \) to \( \text{GND} \) (either the positive or the negative), so that the output voltage levels only comprise the values of the supply voltages (and the symmetrical negative values). The proposed policy sets both ends to any voltage, so that the output voltage levels also comprise the values of the voltage difference between supply voltages.

In general, in the full-bridge topology, the maximum number of distinct output voltage levels is

\[
N_{\text{max}} = 1 + \frac{(n + 2)!}{n!}
\]  

Nevertheless, \( N_{\text{max}} \) will only be achieved if the value of each supply voltage and the value of each voltage difference between
any two of the supply voltages are distinct. If this condition is not satisfied, the number of effective output voltage levels becomes lower.

There are some values of the supply voltages which are particularly interesting, those which yield equally distributed output voltage levels, because they allow simpler modulation schemes. Table I compares the maximum number of distinct output voltage levels that can be generated using a conventional policy and the proposed policy, and the supply voltages that yield equally distributed output levels.

D. Switch Dimensioning for Equalised Conduction Losses and Synthesis with Power MOSFETs

When designing a multi-level converter, not all the switches handle the same current, so their ON resistance can be optimised. A possible design criterion for dimensioning the switches is their static (DC) power consumption (similar conduction losses in all switches).

Let us assume that the ON resistance \( R_{S_i} \) of the switches is always much lower than the complex load impedance at any frequency (let \( Z_L \) be the complex load minimum impedance)

\[
R_{S_i, S'_i} \ll Z_L \leq |Z_{CL}(j\omega)| \quad \forall \omega \in \mathbb{R} \quad i = \{G, 0, 1, \cdots, n\} \quad (2)
\]

Using this approximation and assuming that the output voltage level \( V_o^a \) results in the highest current possible through the switch \( S_a \), the power loss in this switch is

\[
P_{S_a} = R_{S_a} \cdot I_{S_a}^2 = R_{S_a} \cdot \left( \frac{V_o^a}{Z_L} \right)^2 \quad (3)
\]

Let \( V_o^a \) be the highest available output voltage level in the system, and let \( S_a \) be a switch generating this level. At this level, the switch \( S_a \) is going to handle the highest current (it must have the lowest ON resistance). Its power loss can be used as design reference; if so, the other switches \( S_i, S'_i \) may have higher ON resistance as the current through them is going to be lower. Therefore, in the example of the switch \( S_a \), its ON resistance must fulfil

\[
P_{S_a} \leq P_{S_a} \rightarrow R_{S_a} \leq R_{S_a} \cdot \left( \frac{V_o^a}{V_o} \right)^2 \quad (4)
\]

Nonetheless, the switches \( S_i, S'_i, i = \{0, \ldots, n-1\} \) must handle bidirectional currents and withstand positive and negative voltages across them. When synthesising them with power MOSFETs, the built-in body diodes should never conduct, therefore each of these switches must be synthesised with two back-to-back power MOSFETs (Figure 2). The ON resistance of a switch must not depend on how it is synthesised, hence the ON resistance of each back-to-back power MOSFET must be half that of the switch that they implement.

Let us consider a simple example, a full-bridge converter whose supply voltages are GND, 1 V, and 3 V; the switches are synthesised with power MOSFETs. The output voltage levels are: ±3 V, ±2 V, ±1 V and 0 V. Applying these values to the expression (4), the ON resistance of the intermediate switches \( (S_0 \) and \( S'_0 \)) can be 2.25 times higher than that of the others; nevertheless, because of the back-to-back synthesis, the ON resistance of each power MOSFET must be half of that value (1.13). Considering that the size of a power MOSFET is inversely proportional to its ON resistance, the area required by each switch \((S_0 \) and \( S'_0 \)) consisting of two back-to-back power MOSFETs is 1.78 times the area of a single power MOSFET switch (i.e. \( S_{G}, S_{0}, S_{1} \) or \( S'_{1} \)).

### Table I

<table>
<thead>
<tr>
<th>Supply Voltages</th>
<th>Conventional Policy</th>
<th>Proposed Policy</th>
</tr>
</thead>
<tbody>
<tr>
<td>( n = 0 )</td>
<td>( 3 ) (1.0)</td>
<td>( 3 ) (1.0)</td>
</tr>
<tr>
<td>( n = 1 )</td>
<td>(0.5 1.0)</td>
<td>(0.5 1.0)</td>
</tr>
<tr>
<td>( n = 2 )</td>
<td>(0.3 0.6 1.0)</td>
<td>(0.3 0.6 1.0)</td>
</tr>
</tbody>
</table>

III. MULTI-LEVEL PULSE-WIDTH MODULATION

In general, the output voltage levels in multi-level switching converters are not necessarily equally distributed. Therefore, a suitable multi-level modulation to drive these converters must be able to handle non-regularly separated levels (native multi-level modulation).

A. Multi-Level Encoding Process

Pulse-Width Modulation (PWM) is the most common modulation in switching amplifiers (including multi-level with multiple carriers [1]). The encoding process is performed by comparing the reference signal with a carrier signal (generally a sawtooth or a triangle).

This modulation can be extended to native multi-level (N-PWM) by using carriers between each output voltage level (Figure 3). Within each carrier, the encoded signal is generated as in a regular PWM. In order to keep the properties of PWM, thus encoding at constant frequency, the adjacent carriers must be phase shifted 180° (Figure 3). Otherwise the reference signal could elude the corresponding carrier and skip some pulses.

B. Slew-Rate Limit

PWM has an intrinsic limit concerning the carrier frequency: the reference signal’s slew-rate must be lower than that of the carrier [3], [4]. In the multi-level version, this intrinsic limit becomes more restrictive, since the carrier slew rate is reduced. Let \( N \) be the number of output voltage levels, \( c \) the modulation depth, \( A \) the amplitude of a sinusoid sweeping all the output dynamic range and \( A' \) the minimum distance between two consecutive levels. The limit for N-PWM is

\[
\frac{f_{PWM}}{f_c} \geq \frac{\pi \cdot c}{2} \cdot (N - 1) \geq \frac{\pi \cdot c}{2} \cdot \frac{A}{A'} \quad (5)
\]

where \( f_{PWM} \) stands for the carrier frequency and \( f_c \) stands for the reference signal frequency. If the \( N \) levels are regularly separated (best case), the ratio \( A/A' \) simplifies to \( N - 1 \). Notice that even in this case this condition is very restrictive, e.g. if using seven regularly separated levels and 100% of modulation depth, the ratio of the carrier frequency to the reference signal must be higher than 9.43.

If the previous condition is not satisfied, the reference signal may be faster than the carrier, hence the encoded signal may not be a pure PWM signal thus containing extra pulses. From another standpoint, given a certain reference signal and a desired switching frequency, it may be necessary to switch between non-adjacent levels to properly track the reference signal. However, N-PWM needs switching between adjacent levels.

IV. PERFORMANCE OF MULTI-LEVEL AMPLIFIERS

Four multi-level full-bridge amplifiers have been compared (see Figure 4 and Table II). Each amplifier uses a specific number of output voltage levels, yet equally distributed in all cases, including: two supply voltages (three levels), three supply voltages and a conventional policy (five levels), three supply voltages and the proposed policy (seven levels) and four supply voltages and the proposed policy (thirteen levels). The reference signal used in this characterisation is
a band-limited flat-spectrum signal which sweeps all the available dynamic range without clipping.

The main advantage of multi-level amplification is the out-of-band\(^3\) power reduction in the encoded signal (Figure 4). In this way, less filtering effort is required to achieve the same performance. These simulations are quantitatively summarised in Table II, which shows the power distribution. The out-of-band power is reduced by 6 dB in the 5-level case, by 9 dB in the 7-level case and by 15 dB in the 13-level case.

If the output voltage levels are not equally distributed, the amplifier will behave as a multi-level amplifier with fewer levels; e.g. if \(V_0^V = 1.0\, \text{V}\) and \(V_1^V = 2.1\, \text{V}\), the output voltage levels will be \(\pm 2.1\, \text{V}, \pm 1.1\, \text{V}, \pm 1.0\, \text{V}\) and \(0\, \text{V}\), hence the advantage of using the additional \(\pm 1.1\, \text{V}\) levels may not yield a performance improvement (the amplifier performance will be similar to a 5-level one).

A. Filter-Less Amplifiers

In certain applications, such as audio, high-frequency distortion is tolerable, thus filter-less operation is possible. The main drawback of filter-less amplifiers—apart from EMI—is efficiency, since all the out-of-band power can be considered as losses. Besides, all this high-frequency power is directly supplied to the load, which may compromise its reliability.

In a conventional full-bridge amplifier (three levels), the out-of-band power is 50%; in a conventional 5-level amplifier (three supply voltages) it is 21% (Table II). These values, which would be losses in a filter-less amplifier, are too high for a switching amplifier. However, if using a 7-level amplifier (yet three supply voltages but employing the proposed switching policy), the out-of-band power is only 11%.

Notice that a boost converter is often required to achieve the desired output power (e.g. audio in mobile applications), thus three supply voltages (including \(GND\)) are already present in the system; the 7-level converter takes full advantage of the three of them.

By using another additional supply voltage (thirteen levels), the out-of-band power is only 3%. However, generating the additional supply voltage (if it is not already present) involves more losses, which must also be taken into account.

V. Conclusions

This work has proposed a switching policy for multi-level full-bridge switching power converters, that maximises the number of output voltage levels for a given number of supply voltages and connection switches. This is achieved by also using the voltage difference between supply voltages. This work has also analysed a multi-level modulation (\(N\)-PWM) to drive these converters, targeting high-efficiency power amplifiers.

Both the converters and the modulation presented in this work are able to handle arbitrarily separated levels, thus allowing to take advantage of any available supply voltage present in a certain system.

Simulation results show that when tracking a band-limited signal, the out-of-band power can be significantly reduced by using the proposed policy; e.g. upgrading an amplifier from five levels to seven levels (neither additional supply voltages nor additional switches are required) yields an out-of-band power reduction from 21% to 11%.

If some out-of-band distortion is tolerable, filter-less amplification becomes feasible, since the out-of-band power (i.e. losses) is significantly reduced. Employing the proposed policy and four supply voltages (yielding thirteen levels), the out-of-band power is only 3%.

ACKNOWLEDGMENTS

Partial funding by project TEC2007-67988-C02-01 from the Spanish MCYT and EU FEDER funds. This work has been partially supported by the grant RUE CSD2009-00046, Consolidador-Ingenio 2010 Programme, Spanish Ministry of Science and Innovation. With the support of the Commissioner for Universities and Research of the Department of Innovation, Universities and Companies of the Catalan Government and the European Social Fund.

REFERENCES